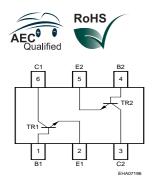
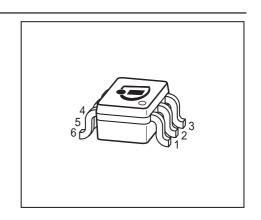


#### **NPN Silicon RF Transistor\***

- For low noise, high-gain broadband amplifiers at collector currents from 2 mA to 30 mA
- $f_T$  = 8 GHz, F = 0.9 dB at 900 MHz
- Two (galvanic) internal isolated
  Transistor in one package
- For orientation in reel see package information below
- Pb-free (RoHS compliant) package 1)
- Qualified according AEC Q101
- \* Short term description





ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration					Package	
BFS483	RHs	1=B	2=E	3=C	4=B	5=E	6=C	SOT363

<sup>&</sup>lt;sup>1</sup>Pb-containing package may be available upon special request



	<b>—</b> 4:
MISVIMILM	Datinac
Maximum	RAIIIUS
MAXILLALL	1 14411190

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$	12	V
Collector-emitter voltage	V <sub>CES</sub>	20	
Collector-base voltage	$V_{\mathrm{CBO}}$	20	
Emitter-base voltage	V <sub>EBO</sub>	2	
Collector current	IC	65	mA
Base current	I <sub>B</sub>	5	
Total power dissipation <sup>1)</sup>	P <sub>tot</sub>	450	mW
<i>T</i> <sub>S</sub> ≤ 40 °C			
Junction temperature	$T_{i}$	150	°C
Ambient temperature	$T_{A}$	-65 150	
Storage temperature	$T_{\rm stg}$	-65 150	
Thermal Resistance			
Parameter	Symbol	Value	Unit
Junction - soldering point <sup>2)</sup>	R <sub>thJS</sub>	≤ 245	K/W

## **Electrical Characteristics** at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol		Values		
		min.	typ.	max.	
DC Characteristics	•			•	•
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	12	-	-	V
$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$					
Collector-emitter cutoff current	I <sub>CES</sub>	-	-	100	μΑ
$V_{CE} = 20 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I <sub>CBO</sub>	-	_	100	nA
$V_{\rm CB} = 10 \text{ V}, I_{\rm E} = 0$					
Emitter-base cutoff current	I <sub>EBO</sub>	-		1	μΑ
$V_{\rm EB}$ = 1 V, $I_{\rm C}$ = 0					
DC current gain-	h <sub>FE</sub>	70	100	140	_
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, pulse measured					

 $<sup>^{1}</sup>T_{\mbox{\scriptsize S}}$  is measured on the collector lead at the soldering point to the pcb

 $<sup>^2\</sup>mbox{For calculation of}\,R_{\mbox{\scriptsize thJA}}$  please refer to Application Note Thermal Resistance



**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter Parameter $I_A = 25^{\circ}$ C, unless $I_A = 25^{\circ}$ C, unless $I_A = 25^{\circ}$ C.	Symbol		Unit		
		min.	typ.	max.	
AC Characteristics (verified by random sampling)					
Transition frequency	$f_{T}$	6	8	-	GHz
$I_{\rm C}$ = 25 mA, $V_{\rm CE}$ = 8 V, $f$ = 500 MHz					
Collector-base capacitance	C <sub>cb</sub>	-	0.34	0.54	pF
$V_{\text{CB}} = 10 \text{ V}, f = 1 \text{ MHz}, V_{\text{BE}} = 0$ ,					
emitter grounded					
Collector emitter capacitance	C <sub>ce</sub>	-	0.13	-	
$V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,					
base grounded					
Emitter-base capacitance	C <sub>eb</sub>	_	1.1	-	
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$ ,					
collector grounded					
Noise figure	F				dB
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
f = 900 MHz		-	0.9	-	
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
f = 1.8 GHz		-	1.4	-	
Power gain, maximum stable <sup>1)</sup>	G <sub>ms</sub>	-	19	-	dB
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ , $Z_{\rm L}$ = $Z_{\rm Lopt}$ ,					
f = 900 MHz					
Power gain, maximum available <sup>2)</sup>	G <sub>ma</sub>	-	12.5	-	dB
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ , $Z_{\rm L}$ = $Z_{\rm Lopt}$ ,					
f = 1.8 GHz					
Transducer gain	$ S_{21e} ^2$				dB
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,					
f = 900 MHz		_	15.5	-	
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,					
f = 1.8 MHz		-	10	-	

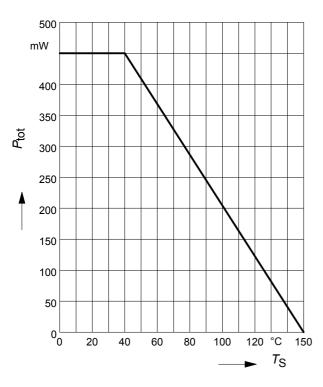
 $<sup>^{1}</sup>G_{ms} = |S_{21} / S_{12}|$ 

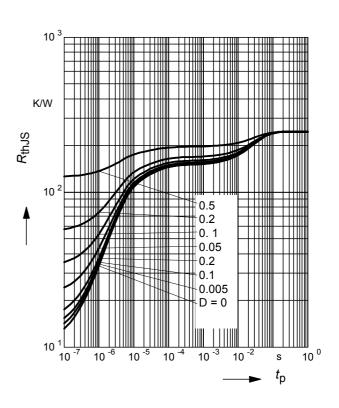
 $<sup>^{2}</sup>G_{\text{ma}} = |S_{21e}/S_{12e}| (k-(k^{2}-1)^{1/2})$ 



# Total power dissipation $P_{tot} = f(T_S)$

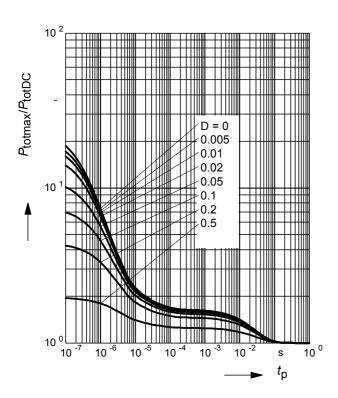
## Permissible Pulse Load $R_{thJS} = f(t_p)$





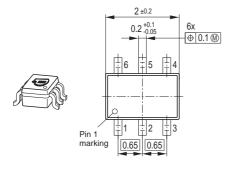
#### **Permissible Pulse Load**

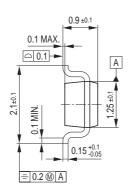
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$$



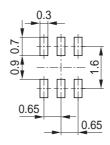


#### Package Outline



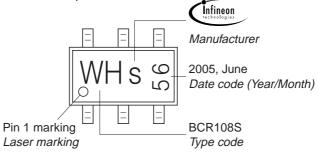


#### Foot Print



## Marking Layout (Example)

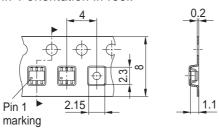
Small variations in positioning of Date code, Type code and Manufacture are possible.



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.





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